

SSC7002KGS6

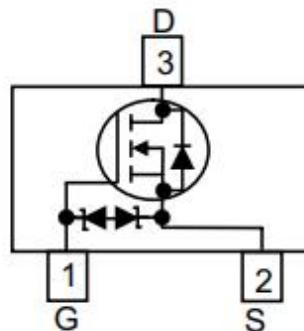
N-Channel Small Switching MOSFET with ESD Protection

➤ Features

VDS	VGS	RDS(on) Typ.	ID	ESD
60V	±20V	2R@10V 3R@4V5	0.3A	1kV

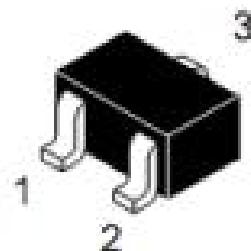
➤ Pin configuration

Top view



➤ Description

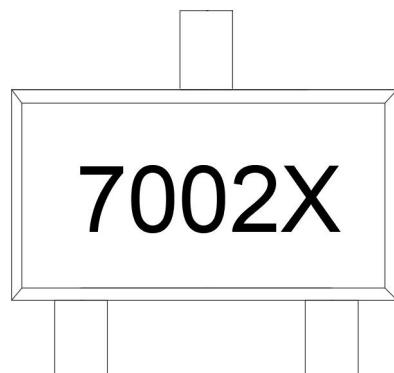
This device is an N-Channel enhancement mode MOSFET, with low on-resistance, fast switching speed and low threshold voltage, it is ideal for portable equipment.



SOT23

➤ Applications

- Direct Logic-Level Interface:
TTL/CMOS
- Drivers: Relays, Solenoids,
Lamps, Hammers
- Display, Memories, Transistors,
etc.
- Battery Operated System
- Solid-State Relays



Marking

➤ Ordering Information

Device	Package	Shipping
SSC7002KGS6	SOT23	3000/Reel

➤ **Absolute Maximum Ratings($T_A=25^\circ\text{C}$ unless otherwise noted)**

Symbol	Parameter	Ratings	Unit
V_{DSS}	Drain-to-Source Voltage	60	V
V_{GSS}	Gate-to-Source Voltage	± 20	V
I_D	Continuous Drain Current ^a	0.3	A
I_{DM}	Pulsed Drain Current ^b	0.8	A
P_D	Power Dissipation ^c	0.83	W
P_{DSM}	Power Dissipation ^a	0.35	W
T_J	Operation junction temperature	-55 to 150	$^\circ\text{C}$
T_{STG}	Storage temperature range	-55 to 150	$^\circ\text{C}$

➤ **Thermal Resistance Ratings($T_A=25^\circ\text{C}$ unless otherwise noted)**

Symbol	Parameter	Typical	Maximum	Unit
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance ^a		357	$^\circ\text{C}/\text{W}$
$R_{\theta JC}$	Junction-to-Case Thermal Resistance		159	

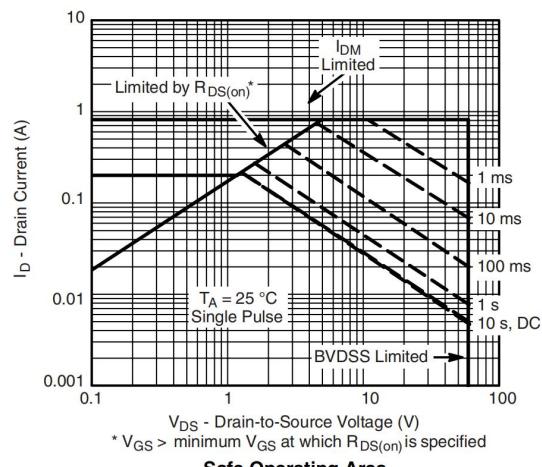
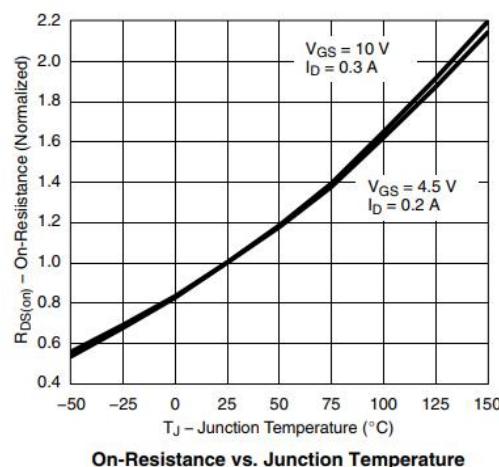
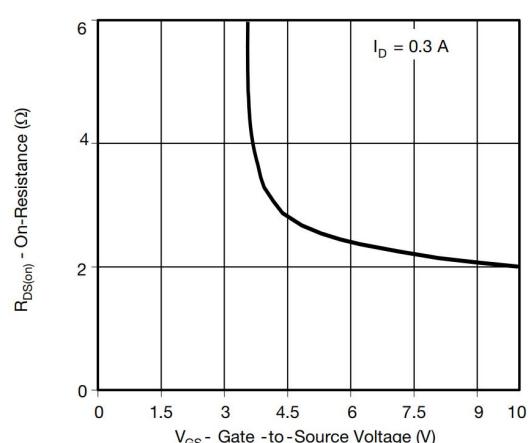
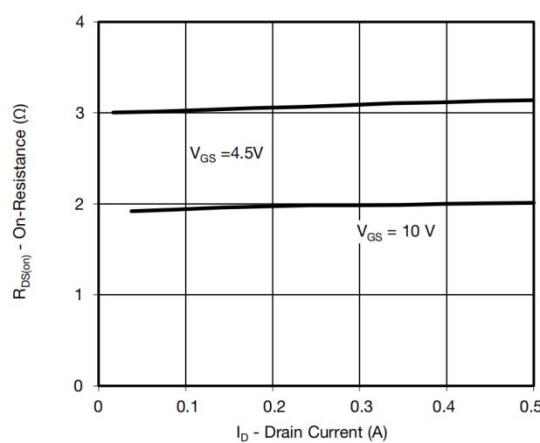
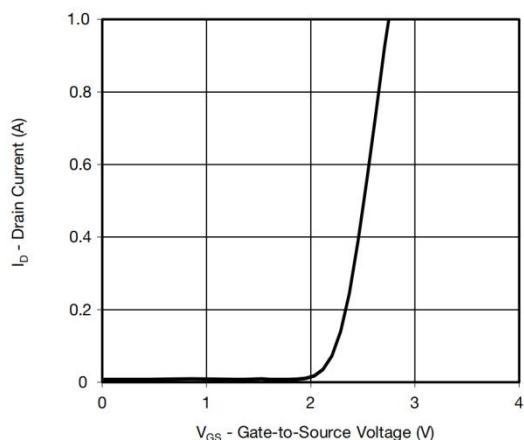
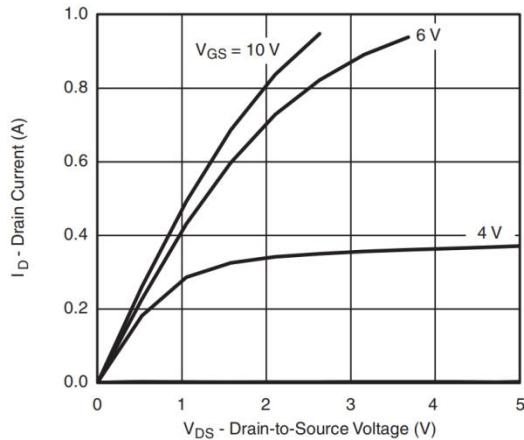
Note:

- a. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in² FR-4 board with 2oz.copper,in a still air environment with $T_A=25^\circ\text{C}$.The value in any given application depends on the user specific board design. The current rating is based on the $t \leq 10\text{s}$ thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation P_D is based on $T_{J(MAX)}=150^\circ\text{C}$, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

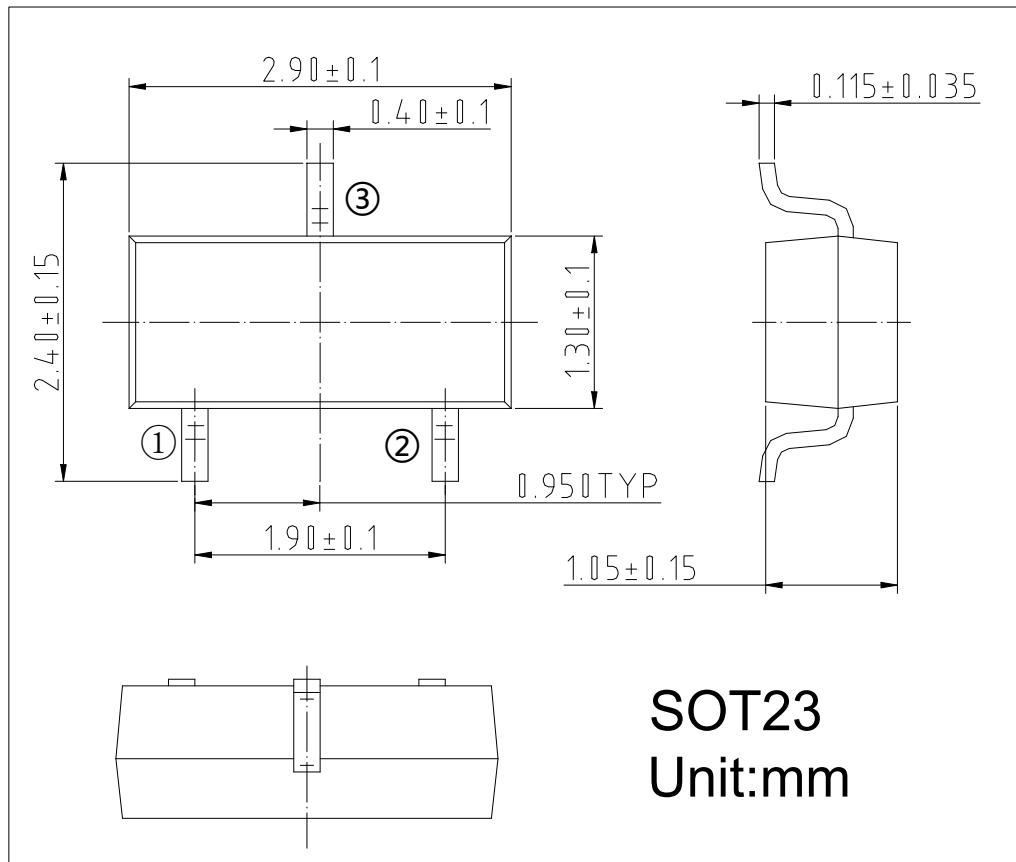
➤ Electronics Characteristics($T_A=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Typ.	Max	Unit
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V, ID=10\mu A$	60			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, ID=250\mu A$	1	1.5	2.0	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V, ID=0.5A$		2	6	R
		$V_{GS}=4.5V, ID=0.05A$		3	8	
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=60V, V_{GS}=0V$			1	μA
I_{GSS}	Gate-Source leak current	$V_{GS}=\pm 20V, V_{DS}=0V$			± 10	μA
G_{FS}	Transconductance	$V_{DS}=10V, ID=0.2A$		0.08		S
V_{SD}	Forward Voltage	$V_{GS}=0V, IS=0.2A$		0.7	1.3	V
C_{iss}	Input Capacitance	$V_{DS}=30V, V_{GS}=0V, f=1MHz$		30	50	pF
C_{oss}	Output Capacitance			13	25	
C_{rss}	Reverse Transfer Capacitance			4.8	10	
$T_{D(ON)}$	Turn-on delay time	$V_{GS}=10V,$ $V_{DS}=20V, RG=20R,$ $RL=60R$		4.6		ns
Tr	Rise Time			4.1		
$T_{D(OFF)}$	Turn-off delay time			24		
T_f	Fall Time			18		
Q_G	Total Gate Charge	$V_{GS}=10V, V_{DS}=15V,$ $ID=0.2A$		0.4		nC
Q_{GS}	Gate Source Charge			0.1		
Q_{GD}	Gate Drain Charge			0.11		

➤ **Typical Characteristics($T_A=25^\circ\text{C}$ unless otherwise noted)**

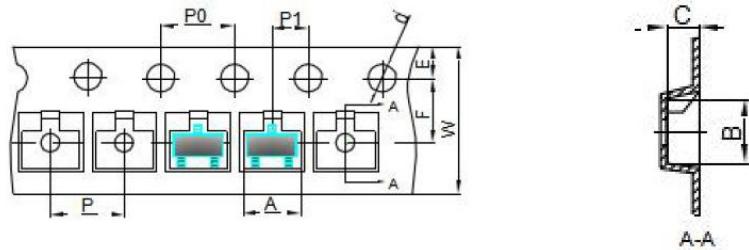


➤ Package Information



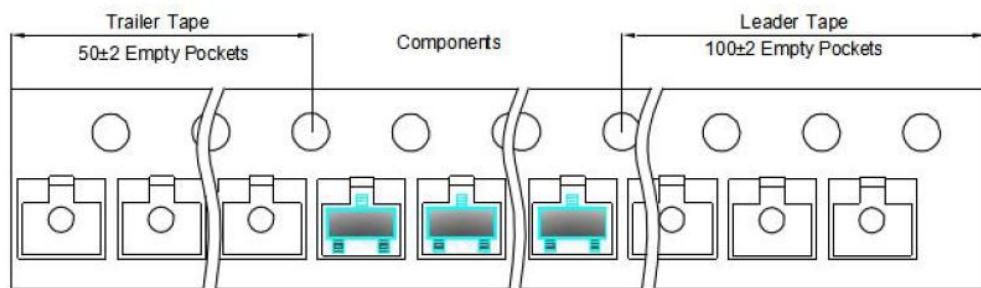
SOT-23 Tape and reel

SOT-23 Embossed Carrier Tape



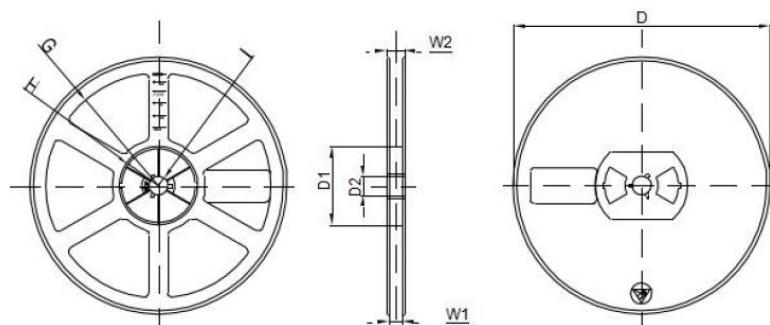
Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15±0.1	2.77±0.1	1.22±0.1	Ø1.50	1.75±0.1	3.5±0.05	4.0±0.1	4.0±0.1	2±0.05	8±0.1

SOT-23 Tape Leader and Trailer



SOT23 带尾(空封 40 格)、带头 (空封 100 格) 空封数

SOT-23 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	Ø54±0.2	13.3±0.2	R79.00	R26.00	R6.50±0.2	9±0.5	12±0.5



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